

on semiconductor® FDS4141-F085

P-Channel PowerTrench[®] MOSFET -40V, -10.8A, 19.0m Ω

Features

- Typ $r_{DS(on)}$ = 10.5m Ω at V_{GS} = -10V, I_D = -10.5A
- Typ $r_{DS(on)}$ = 14.8m Ω at V_{GS} = -4.5V, I_D = -8.4A
- Typ Q_{g(TOT)} = 35nC at V_{GS} = -10V
- High performance trench technology for extremely low r_{DS(on)}
- RoHS Compliant

September-2017, Rev. 1

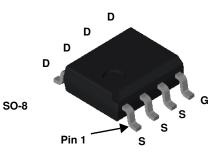
Qualified to AEC Q101

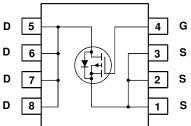
Applications

- Control switch in synchronous & non-synchronous buck
- Load switch
- Inverter









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Publication Order Number: FDS4141-F085/D

Symbol	Parameter	Ratings	Units
V _{DSS}	Drain to Source Voltage	-40	V
V _{GS}	Gate to Source Voltage	±20	V
	Drain Current Continuous (V _{GS} = 10V)	-10.8	
ID	Pulsed	-36	— A
E _{AS}	Single Pulse Avalanche Energy	229	mJ
PD	Power Dissipation	1.6	W
TJ, T _{STG}	Operating and Storage Temperature	-55 to +150	°C

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance Junction to Case	30	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient SO-8, 1in ² copper pad area	81	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDS4141	FDS4141-F085	SO-8	13"	12mm	2500 units

Electrical Characteristics $T_A = 25^{\circ}C$ unless otherwise noted

	Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
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Off Characteristics

B _{VDSS}	Drain to Source Breakdown Voltage	$I_{D} = -250 \mu A, V_{GS} = 0 V$	-40	-	-	V
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -32V,$	-	-	-1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V$,	-	-	±100	nA

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = -250 \mu A$	-1.0	-1.7	-3.0	V
		I _D = -10.5A, V _{GS} = -10V	-	10.5	13.0	
r	Drain to Source On Resistance	$I_D = -8.4A, V_{GS} = -4.5V$	-	14.8	19.0	mΩ
^r DS(on)		$I_D = -10.5A, V_{GS} = -10V, T_J = 125^{\circ}C$	-	15.3	19.0	11122
9 FS	Forward Transconductance	I _D = -10.5A, V _{DD} = -5V		34		S

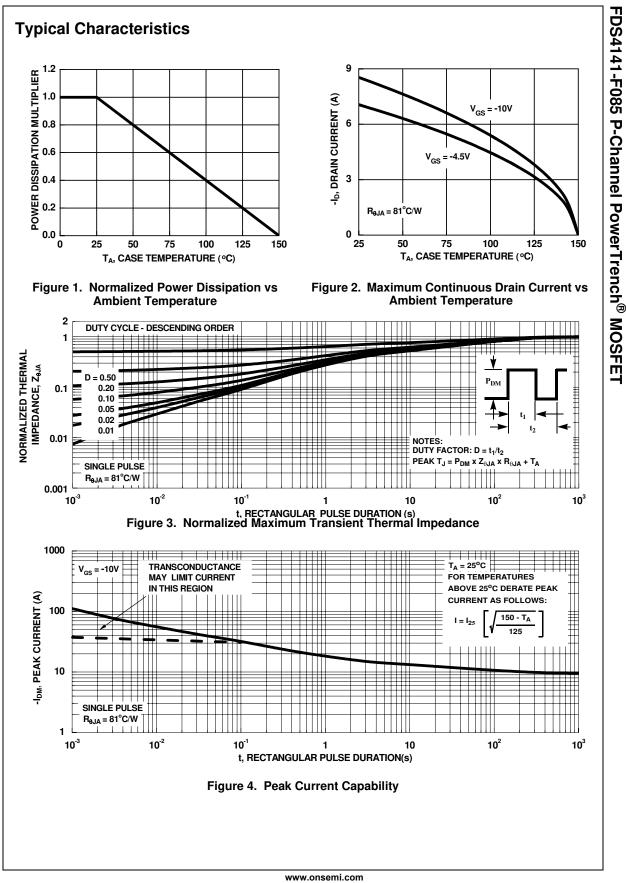
Dynamic Characteristics

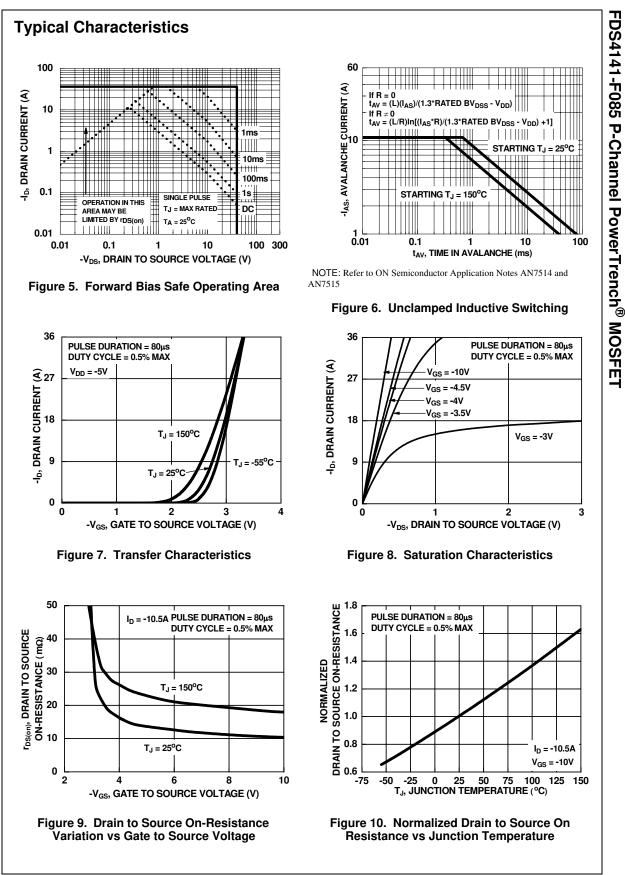
C _{iss}	Input Capacitance		0)/	-	2005	-	pF
C _{oss}	Output Capacitance	V _{DS} = -20V, V _{GS} = f = 1MHz	0ν,	-	355	-	pF
C _{rss}	Reverse Transfer Capacitance			-	190	-	pF
R _g	Gate Resistance	f = 1MHz		-	5.0	-	Ω
Q _{g(TOT)}	Total Gate Charge at -10V	V _{GS} = 0 to -10V		-	35	45	nC
Q _{g(-5)}	Total Gate Charge at -5V	$V_{GS} = 0$ to -5V	V _{DD} = -20V	-	18.6	24.2	nC
Q _{gs}	Gate to Source Gate Charge		I _D = -10.5A	-	5.2	-	nC
Q _{gd}	Gate to Drain "Miller" Charge			-	6.6	-	nC

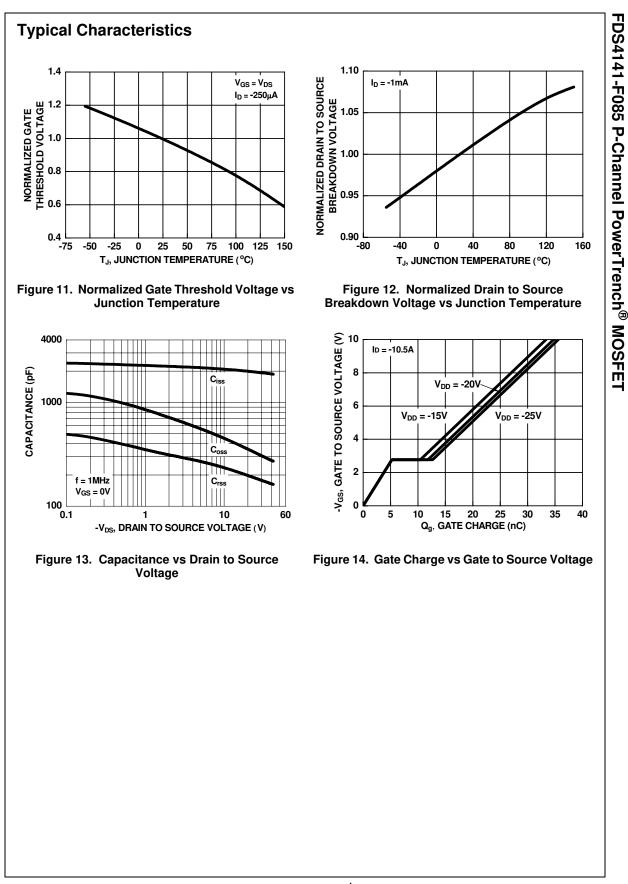
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Switch	ing Characteristics					
t _{on}	Turn-On Time		-	-	25	ns
t _{d(on)}	Turn-On Delay Time		-	9.7	-	ns
t _r	Rise Time	$V_{DD} = -20V, I_D = -10.5A$	-	4.4	-	ns
t _{d(off)}	Turn-Off Delay Time	V_{GS} = -10V, R_{GEN} = 6 Ω	-	41	-	ns
	Fall Time		-	11.6	-	ns
f	Fail Time			11.0	-	115
t _f t _{off}	Turn-Off Time		-	-	84	ns
t _{off} Drain-So		I _{SD} = -10.5A		-0.8	-1.3	-
t _{off} Drain-So V _{SD}	Turn-Off Time Durce Diode Characteristics Source to Drain Diode Voltage		-	-0.8 -0.7	84 -1.3 -1.2	ns V
t _{off} Drain-So	Turn-Off Time Durce Diode Characteristics	I _{SD} = -10.5A	-	-0.8	-1.3	ns

This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: http://www.aecouncil.com/ All ON Semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.

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